





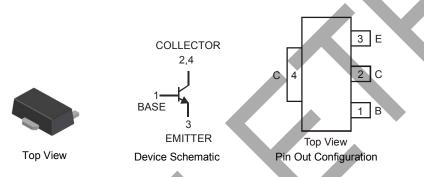
#### LOW V<sub>CE(SAT)</sub> NPN SURFACE MOUNT TRANSISTOR

#### **Features**

- **Epitaxial Planar Die Construction**
- Low Collector-Emitter Saturation Resistance  $R_{CE(SAT)}$  = 75m $\Omega$  at
- Complementary PNP Type Available (2DB1386)
- Ideally Suited for Automated Assembly Processes
- Ideal for Medium Power Switching or Amplification Applications
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)

### **Mechanical Data**

- Case: SOT89-3L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.055 grams (approximate)



#### Maximum Ratings @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	20	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Peak Pulse Current	I <sub>CM</sub>	10	Α
Continuous Collector Current	Ic	5	A

#### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3) @ T <sub>A</sub> = 25°C	$P_{D}$	1	W
Thermal Resistance, Junction to Ambient Air (Note 3) @ T <sub>A</sub> = 25°C	$R_{ heta JA}$	125	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

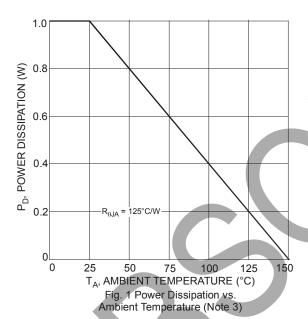
- No purposefully added lead.
  Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead\_free/index.php.
  Device mounted on FR-4 PCB; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.



### Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Conditions
OFF CHARACTERISTICS (Note 4)						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	50	_	_	V	$I_C = 50\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	20	_	_	V	$I_{C} = 1mA, I_{B} = 0$
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	6	_	_	V	$I_E = 50 \mu A, I_C = 0$
Collector Cut-Off Current	I <sub>CBO</sub>	_	_	0.5	μΑ	$V_{CB} = 40V, I_{E} = 0$
Emitter Cut-Off Current	I <sub>EBO</sub>	_	_	0.5	μΑ	$V_{EB} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 4)						
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	_	0.3	1.0	٧	$I_C = 4A, I_B = 0.1A$
DC Current Gain	$h_{FE}$	180	_	390	_	$I_C = 0.5A, V_{CE} = 2V$
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f <sub>T</sub>	_	220		MHz	$V_{CE} = 6V, I_{E} = -50mA$ f = 100MHz
Output Capacitance	C <sub>ob</sub>	_	14		pF	$V_{CB} = 20V, I_{E} = 0,$ f = 1MHz

Notes: 4. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.



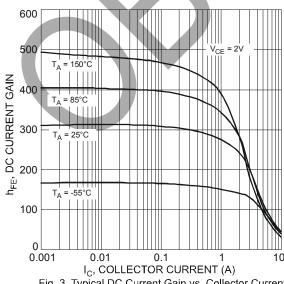
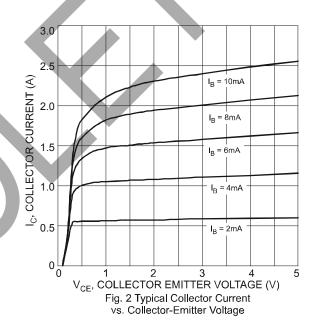


Fig. 3 Typical DC Current Gain vs. Collector Current



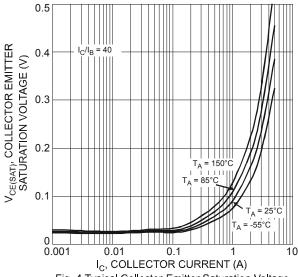
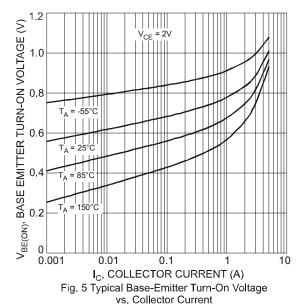
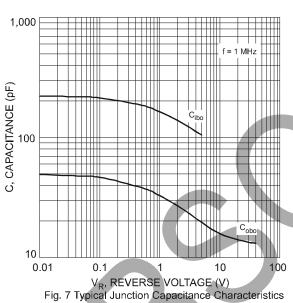


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current







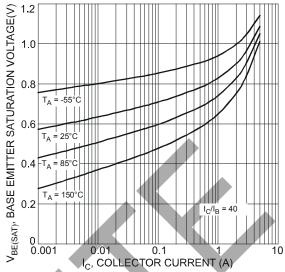


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

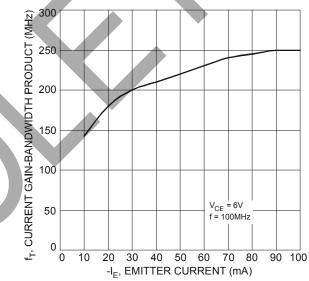


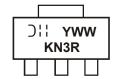
Fig. 8 Typical Gain-Bandwidth Product vs. Emitter Current

#### Ordering Information (Note 5)

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I	Part Number	Case	Packaging
I	2DD2098R-13	SOT89-3L	2500/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

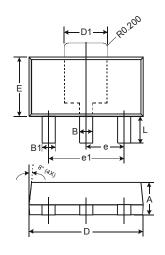
### Marking Information

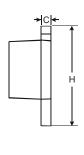


KN3R = Product Type Marking Code YWW = Date Code Marking Y = Last digit of year (ex: 7 = 2007) WW = Week code (01 – 53)



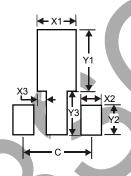
# Package Outline Dimensions





SOT89-3L			
Dim	Min	Max	
Α	1.40	1.60	
В	0.44	0.62	
B1	0.35	0.54	
С	0.35	0.43	
D	4.40	4.60	
D1	1.52	1,83	
Е	2.29	2.60	
е	1.50 Typ		
e1	3.00 Typ		
Н	3.94	4.25	
L	0.89	1.20	
All Dimensions in mm			

## **Suggested Pad Layout**



Dimensions	Value (in mm)
X1	1.7
X2	0.9
Х3	0.4
Y1	2.7
Y2	1.3
Y3	1.9
_	3.0



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